

# Abstracts

## Design and Fabrication Techniques for Lumped-Element GaAs MESFET Power Amplifiers Using Automated Assembly Procedures

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*J.B. Klatskin, R.L. Camisa and D. Haggis. "Design and Fabrication Techniques for Lumped-Element GaAs MESFET Power Amplifiers Using Automated Assembly Procedures." 1982 MTT-S International Microwave Symposium Digest 82.1 (1982 [MWSYM]): 172-174.*

This paper describes the development and fabrication of lumped-element GaAs MESFET power amplifiers. The amplifiers manufactured were designed for both narrow-band and wideband (6-11 GHz) operation. Emphasis is directed toward performance trimming and automated assembly.

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